OPB819Z

Features:

- Non-contact switching
- 24" (609 mm) long wire leads
- 1.25" (31.75 mm) wide slot, 1.38" (35.05 mm) deep slot



Description:

The OPB819Z slotted switch consists of an infrared emitting diode and an NPN silicon phototransistor mounted in an opaque housing with clear windows for dust protection. Switching of the phototransistor occurs whenever an opaque object passes through the slot.

The OPB819Z has an 1.38" (35.05 mm) deep and 1.25" (31.75 mm) wide slot allowing for a longer reach of the optical center line from the mounting plane. The switch housing is designed to use the lens of each component as the optical aperture resulting in an equivalent aperture diameter of 0.06" (1.52 mm).

Applications:

- Non-contact object sensing
- Assembly line automation
- Machine automation
- Equipment security
- Machine safety



Color	Description	Color	Description	
Red	Anode	White	Collector	
Black	Cathode	Green	Emitter	



General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

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Electrical Specifications

Absolute Maximum Ratings (T_A=25°C unless otherwise noted)

Storage & Operating Temperature Range	-40° C to +85° C				
Lead Soldering Temperature [1/16 inch (1.6mm) from the case for 5 sec. with soldering iron] $^{(1)}$	260° C				
Input Diode					
Forward DC Current	50 mA				
Peak Forward Current (1 μs pulse width, 300 pps)	3 A				
Reverse DC Voltage	2 V				
Power Dissipation ⁽²⁾	100 mW				
Output Phototransistor					
Collector-Emitter Voltage	30 V				
Emitter-Collector Voltage	5 V				
Collector DC Current	30 mA				
Power Dissipation ⁽²⁾	100 mW				

Electrical Characteristics (T_A = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	түр	MAX	UNITS	TEST CONDITIONS		
Input Diode								
V _F	Forward Voltage	-	-	1.8	V	I _F = 20 mA		
I _R	Reverse Current	-	-	100	μΑ	V _R = 2.0 V		
Output Phototransistor								
V _{(BR)(CEO)}	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_{c} = 100 \ \mu A, I_{F} = 0, E_{E} = 0$		
V _{(BR)(ECO)}	Emitter-Collector Breakdown Voltage	5	-	-	V	$I_{E} = 100 \ \mu A, \ I_{F} = 0, \ E_{E} = 0$		
I _{CEO}	Collector-Emitter Leakage Current	-	-	100	nA	$V_{CE} = 10 \text{ V}, \text{ I}_{\text{F}} = 0, \text{ E}_{\text{E}} = 0$		
Coupled								
I _{C(ON)}	On-State Collector Current	0.5	-	12.0	mA	V _{CE} = 5 V, I _F = 40 mA		
V _{CE(SAT)}	Collector-Emitter Saturation Voltage	-	-	0.4	V	I _C = 250 μA, I _F = 40 mA		

Notes:

(1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.

(2) Derate linearly 1.67 mW/°C above 25° C.

(3) All parameters tested using pulse techniques.

(4) Methanol or isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones. Spray and wipe. Do not submerge.

(5) Polarity is denoted by color the wires: LED (Anode-Red, Cathode-Black); Phototransistor (Collector-White, Emitter-Green).

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Performance

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0.15

Displacement Distance (inches)

0.20

0.25

0.30

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890 nm

Transistor

1.26" / 1.38"

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None

0.00

0.05

0.10

24" / 26 AWG

Wire

OPB819Z



Revision	Change Description	ECN	Date	Approved
А	Initial Release	xxxxxx		
A.1	Revised and put into new format. Required changes on all pages. Added graphs.	N/A	11/28/05	
A.2	Changed part number in Ordering Information box. Added Polysulphone warning. Updated Graphs	N/A	02/08/06	Bob Procsal
A.2	Lined up titles on pin number box on page 1. Did not put new issue/date.	N/A	03/23/06	
A.3	Changed Ic(on) limits	N/A	06/08/07	
В	Update illustration on page 1	N/A	10/16/14	Cosmin Suciu

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